

Simulations of 65 nm silicon sensors using Allpix Squared

Manuel Alejandro Del Rio Viera

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The Tangerine Project - Towards Next Generation Silicon Detectors

Goal: Design a monolithic pixel detector in 65nm CMOS imaging technology

- **Main application:** beam telescope
- **Potential applications:** linear collider experiments, etc.

Performance targets:

- Position resolution $\leq 3 \mu\text{m}$
- Time resolution $\sim 1 - 10 \text{ ns}$
- Material budget $\sim 50 \mu\text{m Si}$



MIMOSA Beam Telescope, DESY II Test Beam Facility



The Tangerine Project - Towards Next Generation Silicon Detectors

- **The Tangerine project's goal** is to develop the next generation of small collection electrode **monolithic silicon pixel detectors** using the **65 nm CMOS** imaging process.

Monolithic Silicon Pixel Detector using 65 nm CMOS imaging process:

- **Higher logic density**
- **Lower power consumption** (compared to previously used processes).

In monolithic sensors:

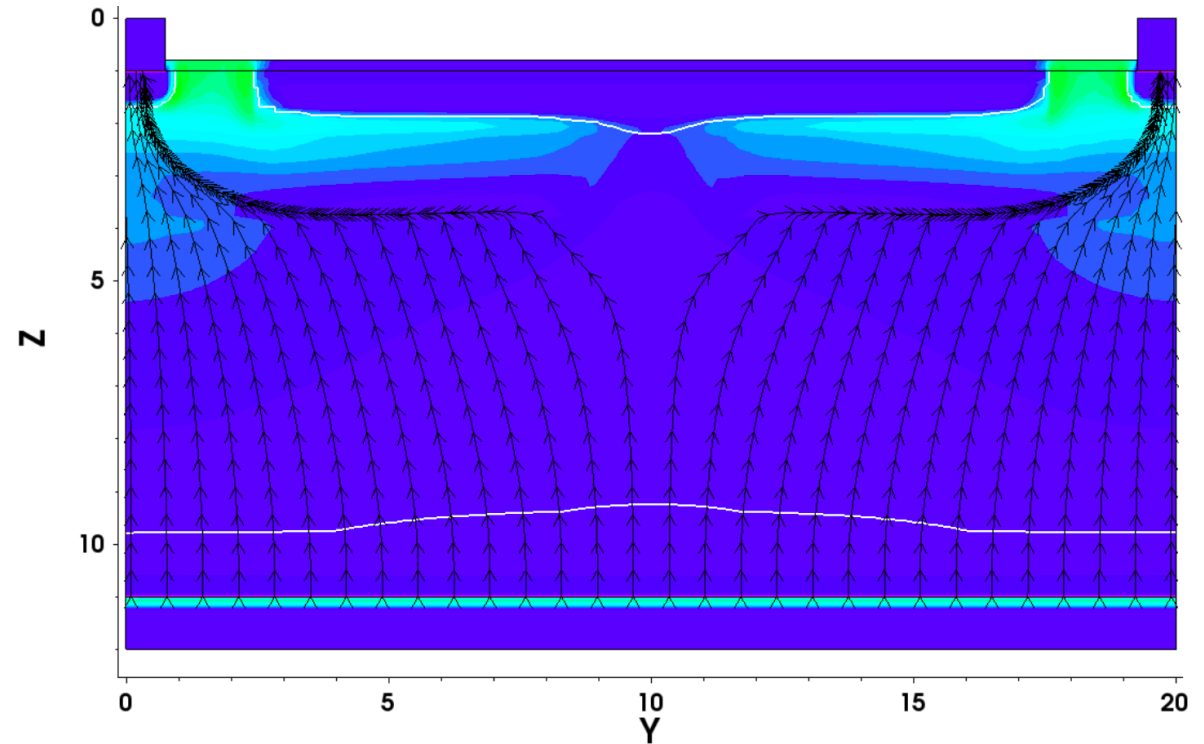
- The **sensitive volume and readout are in a single chip**
- **Lower material budget, and reduced cost and production effort** (compared to hybrid sensors).



Technology computer-aided design (TCAD)

The **electric field** and the **doping concentration** in silicon detectors are certainly **complicated**.

TCAD is utilized in order to obtain this important profiles that characterize the **detector layout**.



SYNOPSYS®

Shoutout to **Anastasiia Velyka**, **Adriana Simancas**,
Larissa Mendes

Allpix Squared (Allpix²)

A combination of **TCAD** and **Monte Carlo (MC)** simulations are used.

```
[ElectricFieldReader]
model = "mesh"
file_name = "ElectricField.apf"
field_offset=0.5,0.5
depletion_depth= 40um
log_level="debug"

[DopingProfileReader]
model = "mesh"
file_name = "DopingConcentration.apf"
field_offset=0.5,0.5
doping_depth= 40um
log_level="debug"
```

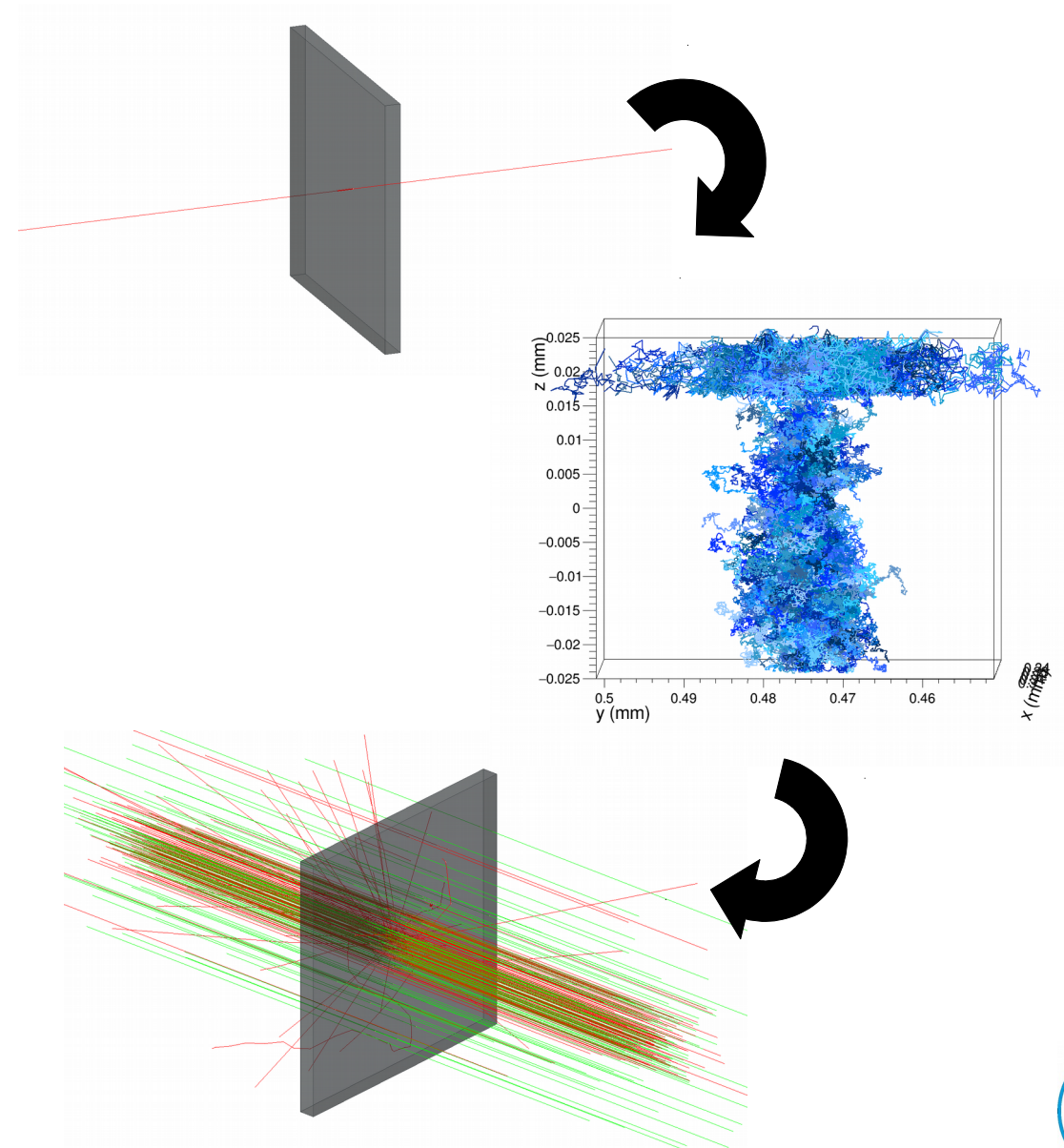
Motivation:

- **Value** of the simulation results
- Reduced **cost**
- **Reproducibility** of performance

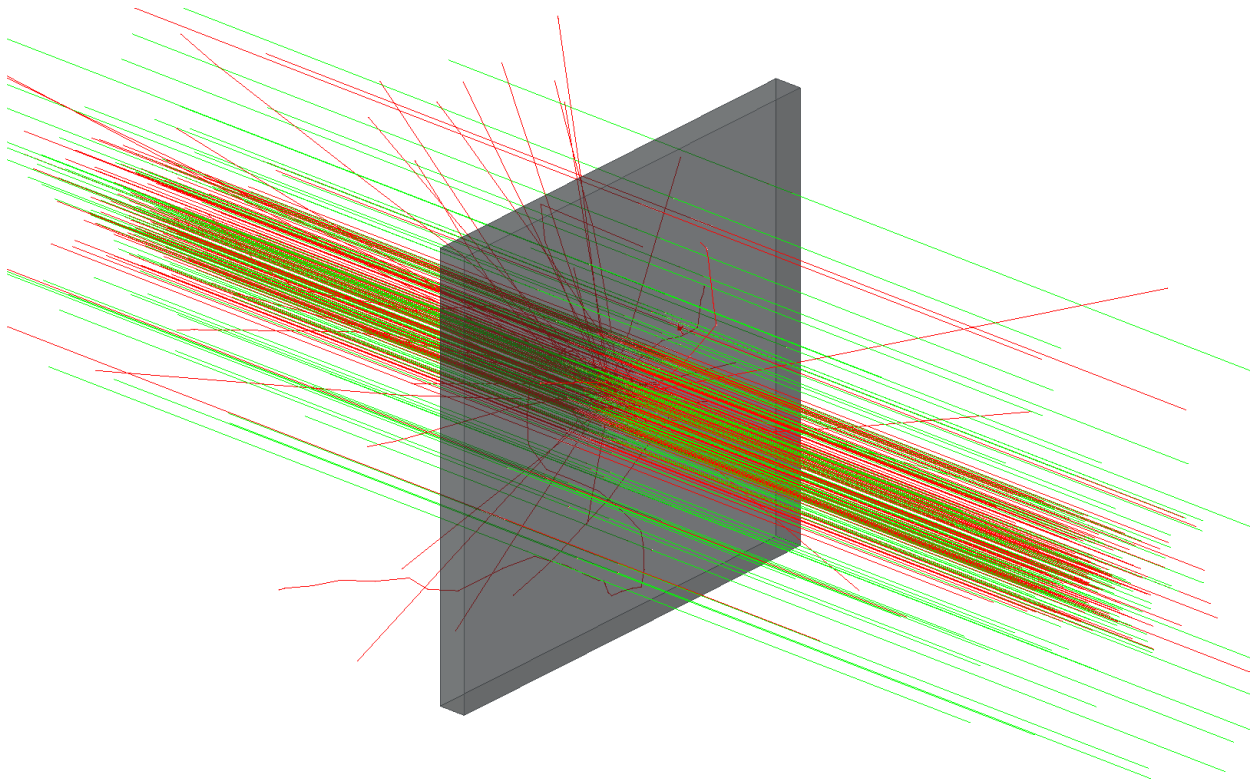


Monte Carlo Setup

- 1) A particle is **randomly** shoot through the sensor.
- 2) **Ionization** (And other Physics processes: Diffusion, Drift, Recombination...).
- 3) **Repetition** (Same energy and direction).
- 4) **Analysis**



Monte Carlo Setup



In our case, the beam is a Gaussian electron beam with a **5 GeV** energy (a **DESY** like type of beam).

The number and size of the pixels in the sensor can be adjusted depending in our needs, a typical size being **20x20 μm^2** .

Important quantities for us to obtain are:

- **Efficiency**
- **Hit Map**
- **Cluster Size and Cluster Charge**
- **Spatial Resolution**
- ...

Simulation Results (Comparison between Mobility Models)

A **mobility model** refers to a model describing the electric field and doping concentration dependence of the charge carrier velocity.

We will compare the following two mobility models:

Jacoboni-Canali

$$\mu(E) = \frac{v_m}{E_c} \frac{1}{(1 + (E/E_c)^\beta)^{1/\beta}},$$

Masetti-Canali

$$\mu(E, N) = \frac{\mu_m(N)}{(1 + (\mu_m(N) \cdot E/v_m)^\beta)^{1/\beta}}$$

Note that Jacoboni model does not depend on the **doping concentration** (explicitly) while Masetti does

Simulation Results (Comparison between Mobility Models)

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$$\mu(E) = \frac{v_m}{E_c} \frac{1}{(1 + (E/E_c)^\beta)^{1/\beta}}$$

```
[GenericPropagation]
temperature = 293K|
mobility_model="jacoboni"
recombination_model = "srh_auger"
charge_per_step = 5
timestep_min = 0.5ps
timestep_max = 0.05ns
integration_time = 25ns
propagate_electrons = true
```

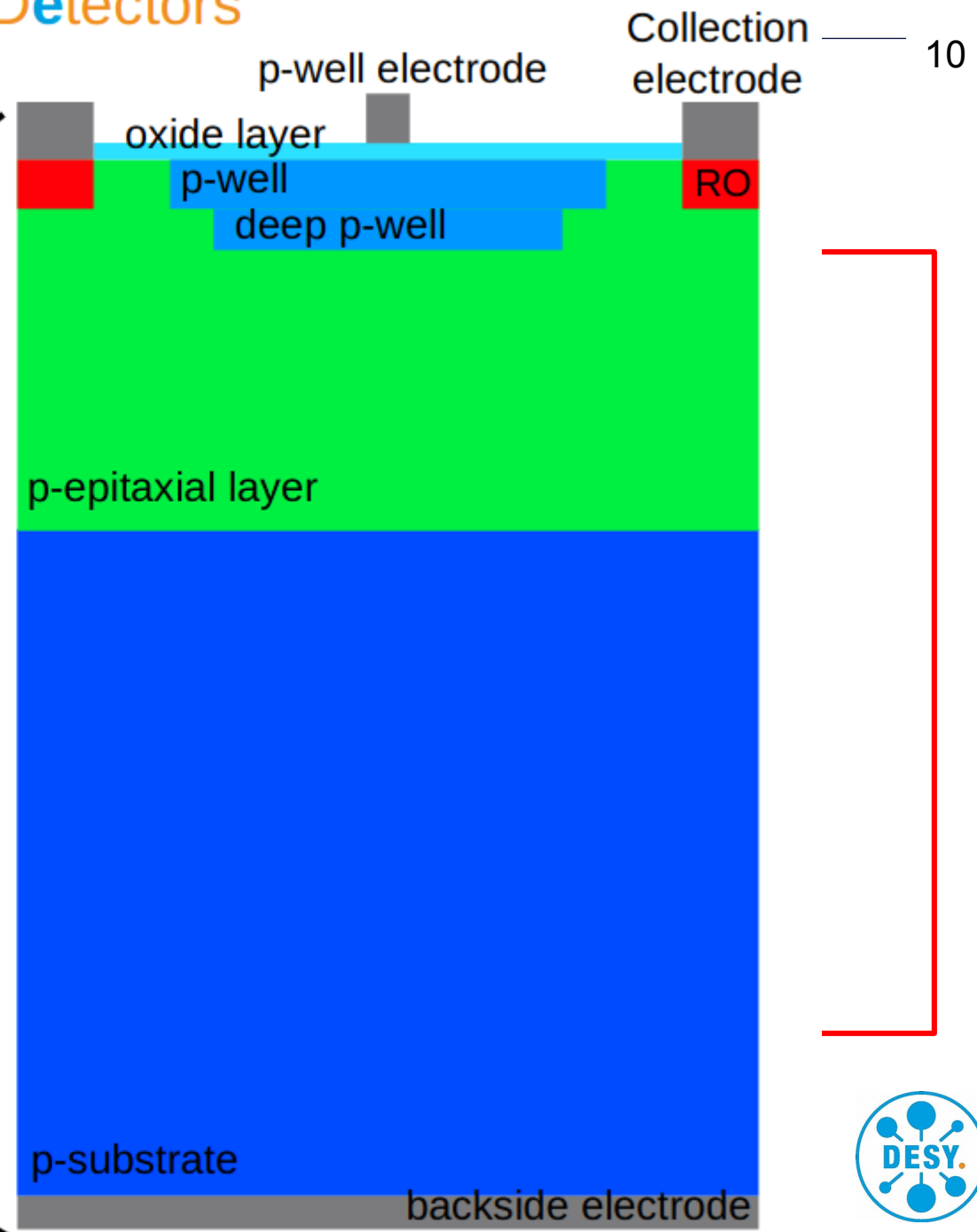
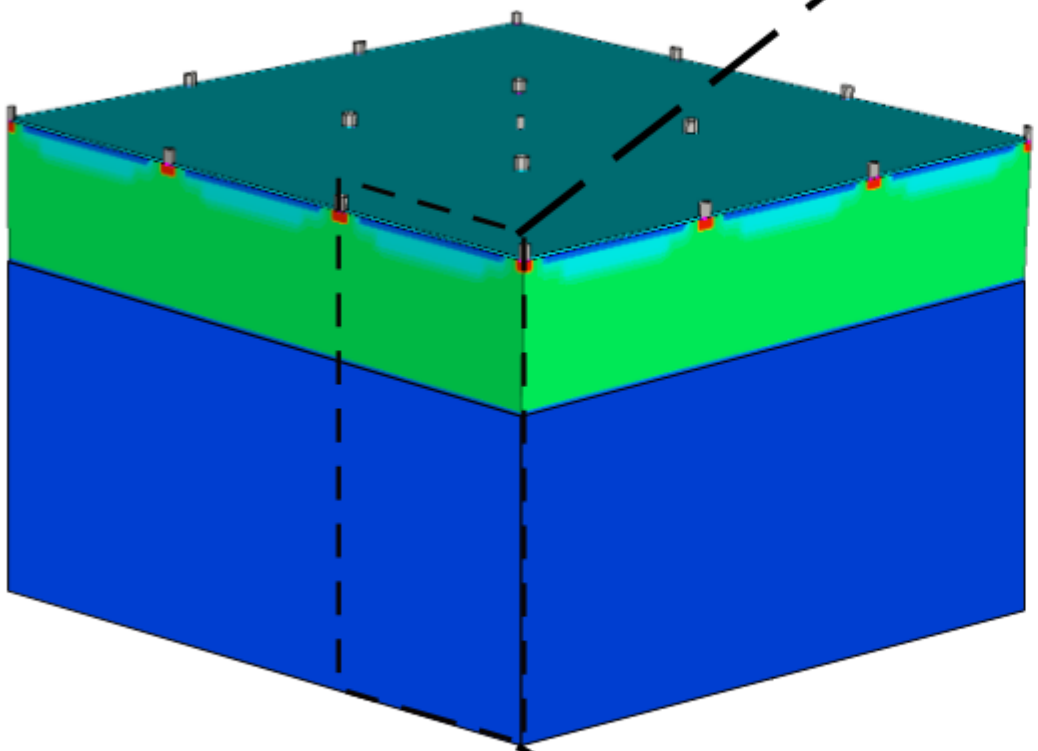
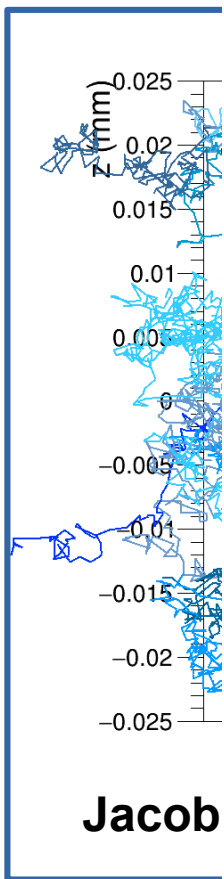
Masetti-Canali

$$\mu(E, N) = \frac{\mu_m(N)}{(1 + (\mu_m(N) \cdot E/v_m)^\beta)^{1/\beta}}$$

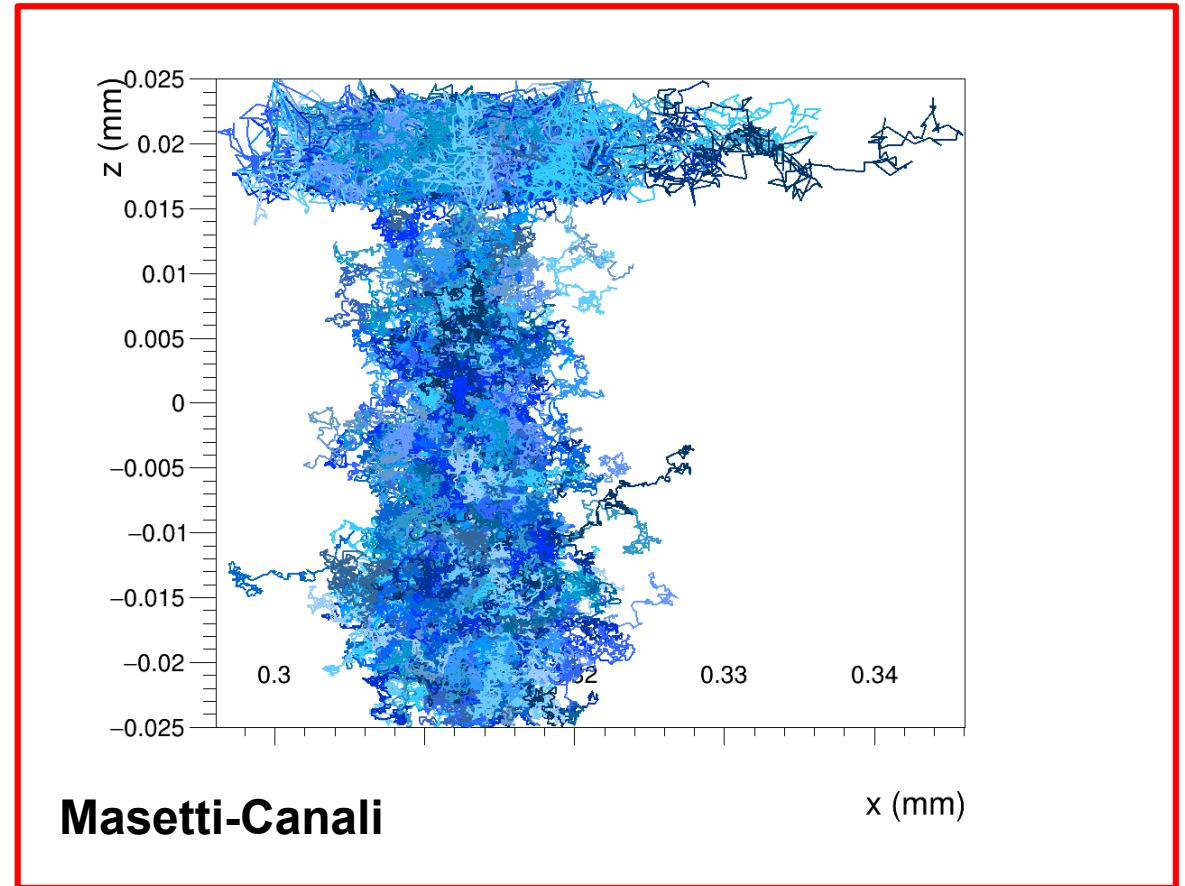
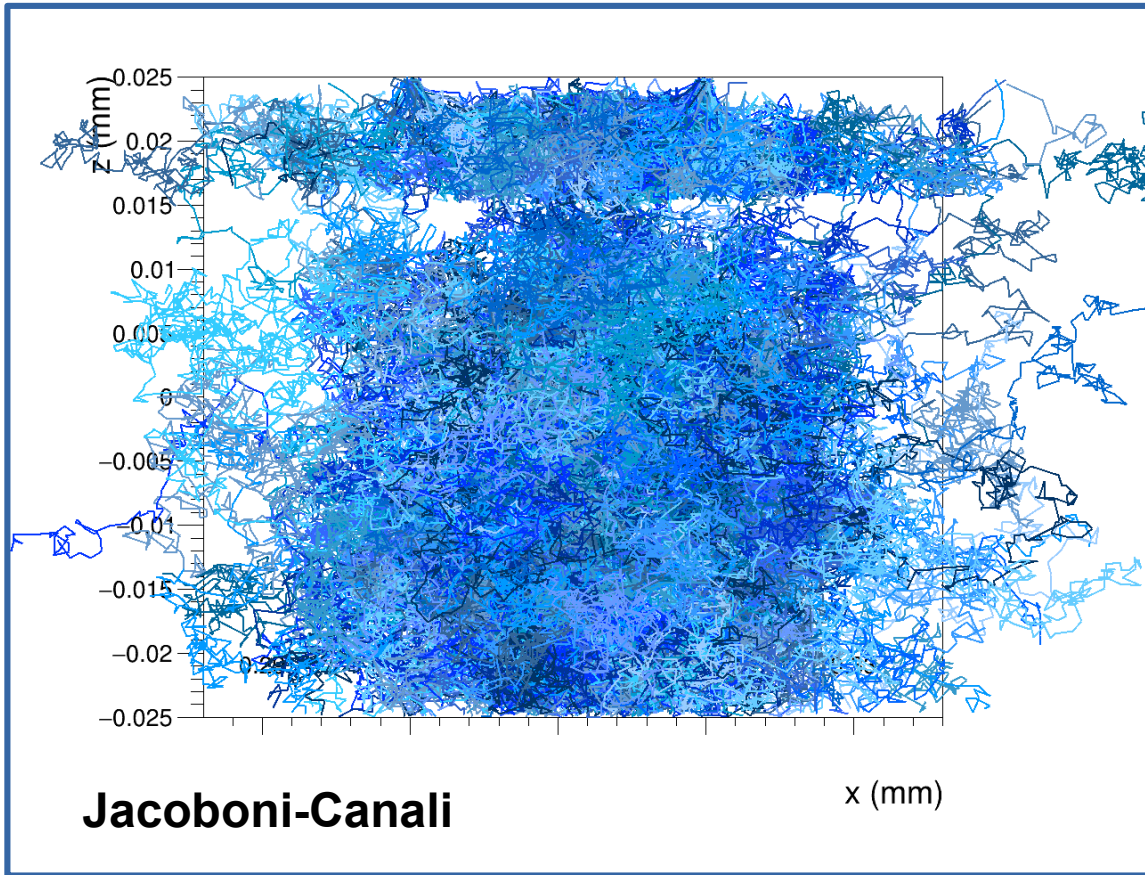
st - Towards Next Generation Silicon Detectors

Simulation of 6:

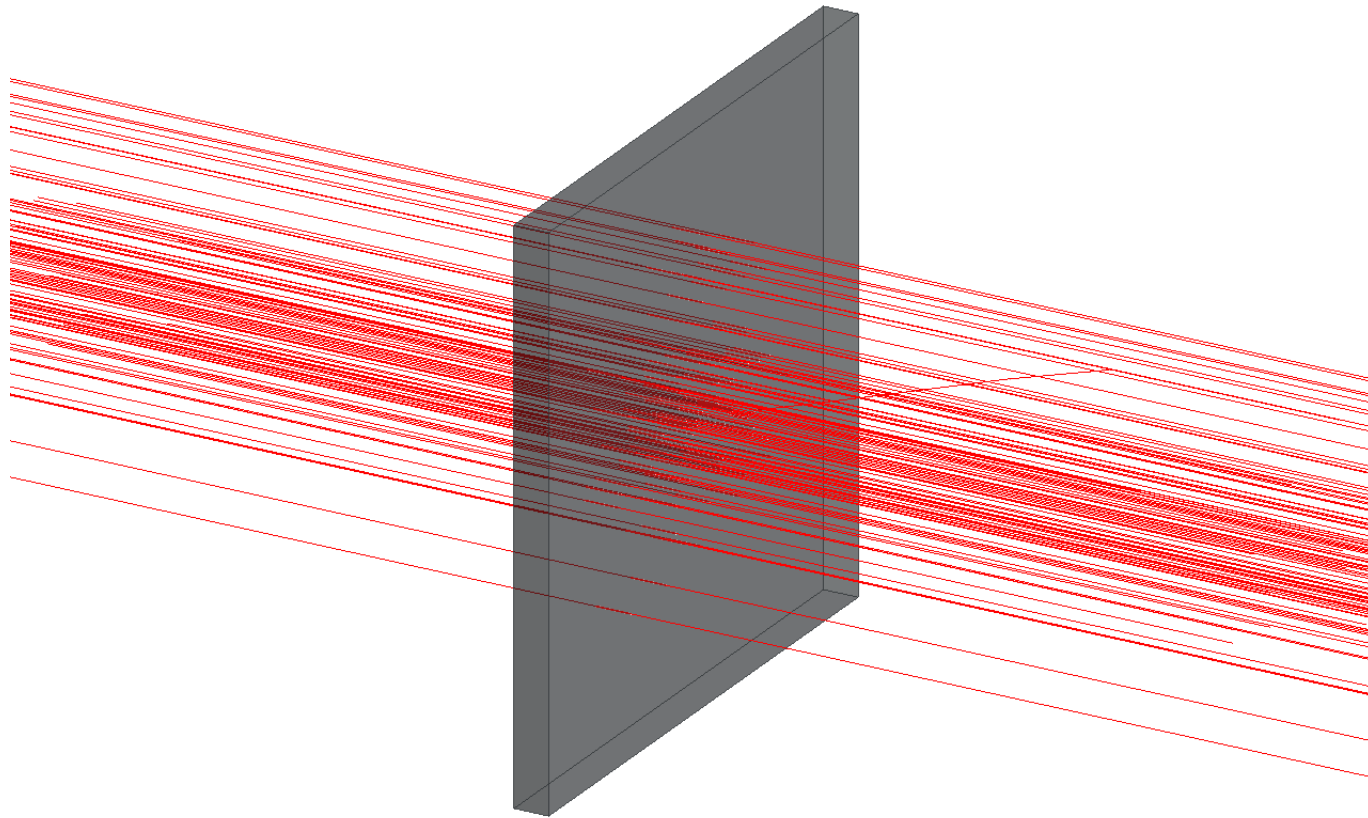
Linegra



Linegraphs `output_linegraphs = true`



Efficiency



$$\text{Efficiency} = \frac{\text{Fired}}{\text{Events}}$$

Fired = Number of Events that fired a pixel

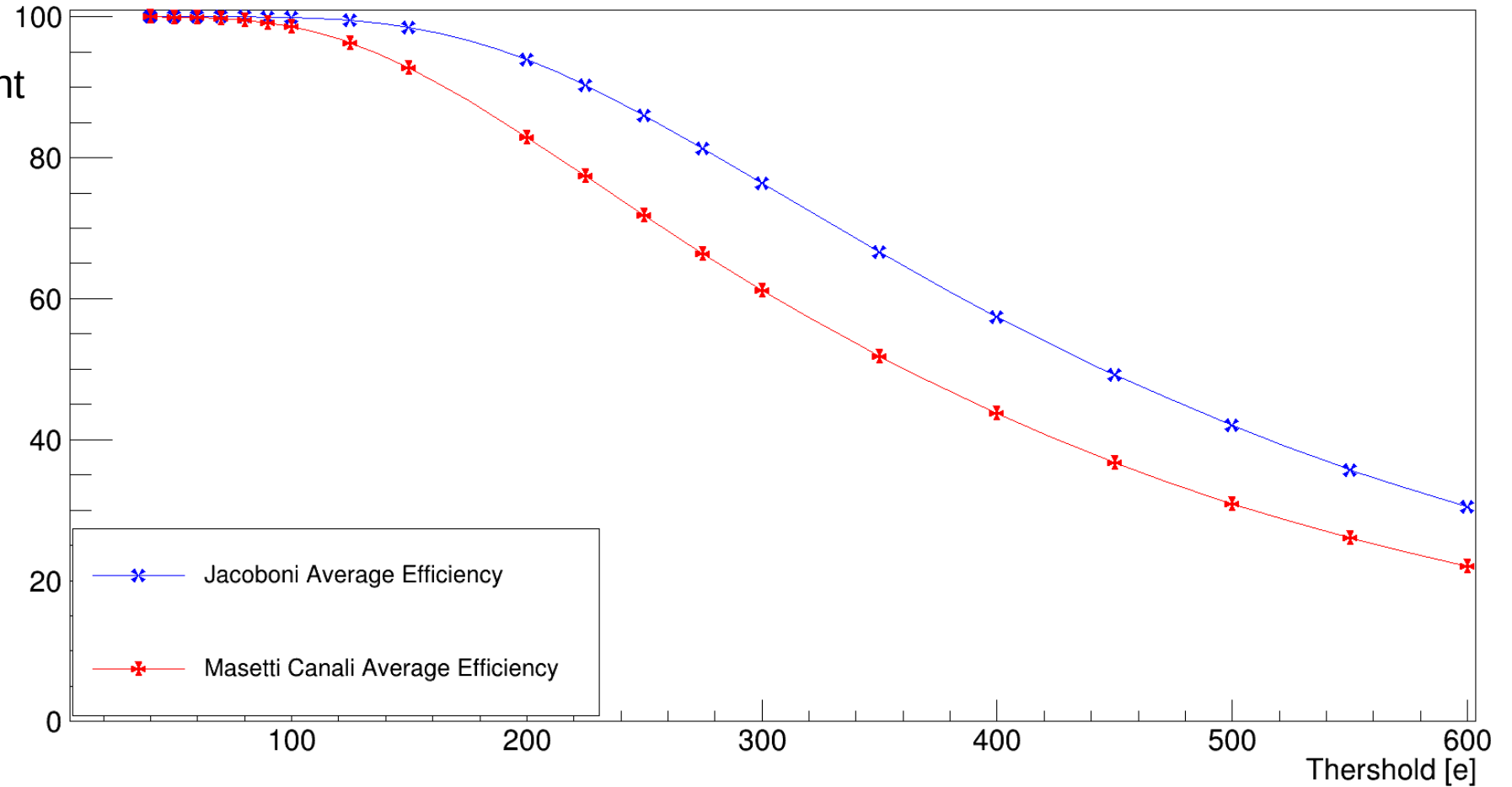
Events = Number of particles shot

Number of events ~ 500000

Efficiency as a function of the detection threshold

Average Efficiency [%]

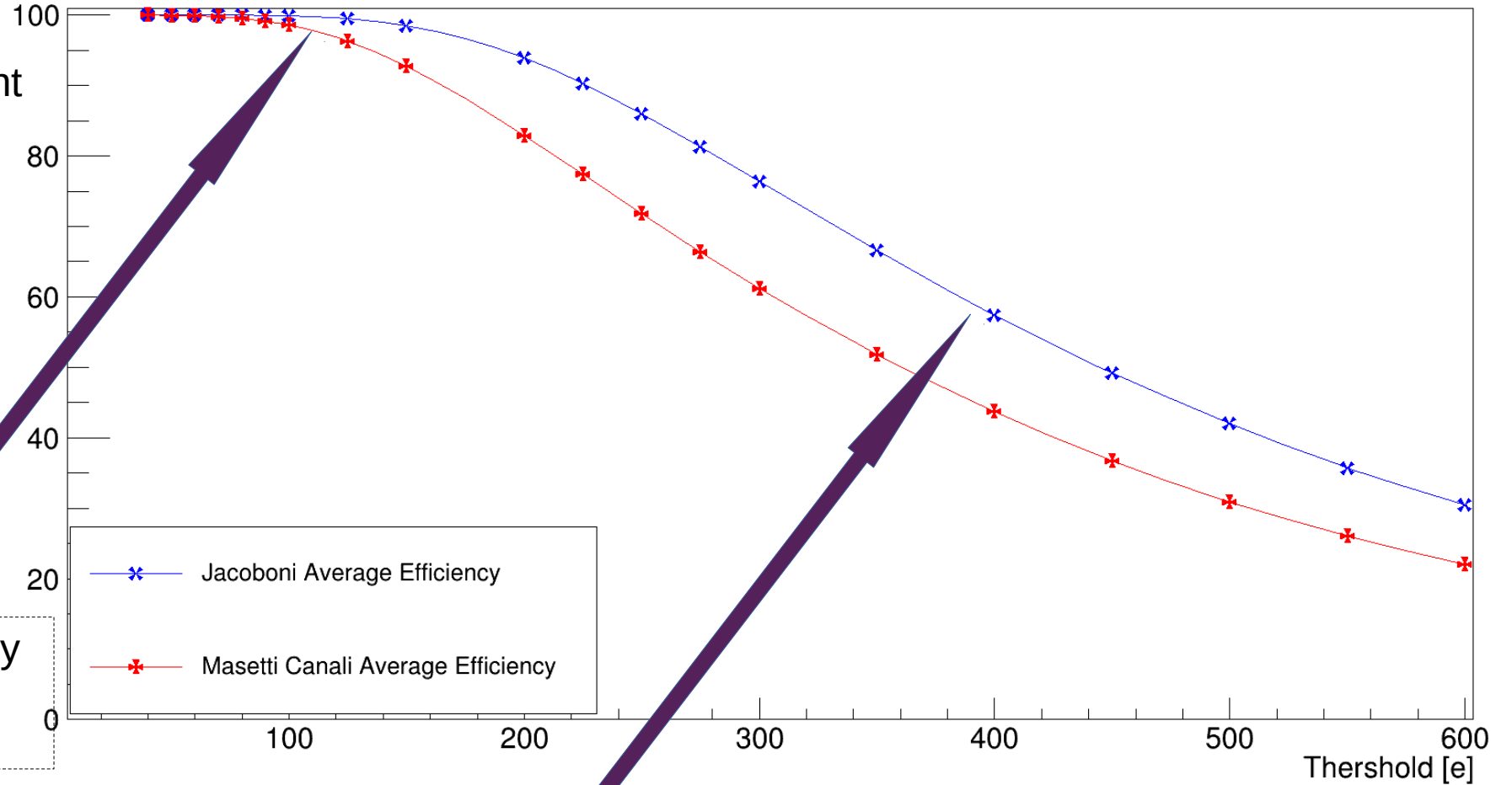
- Non-doping dependent Mobility Model
- Doping dependent Mobility Model



Efficiency as a function of the detection threshold

Average Efficiency [%]

- Non-doping dependent Mobility Model
- Doping dependent Mobility Model

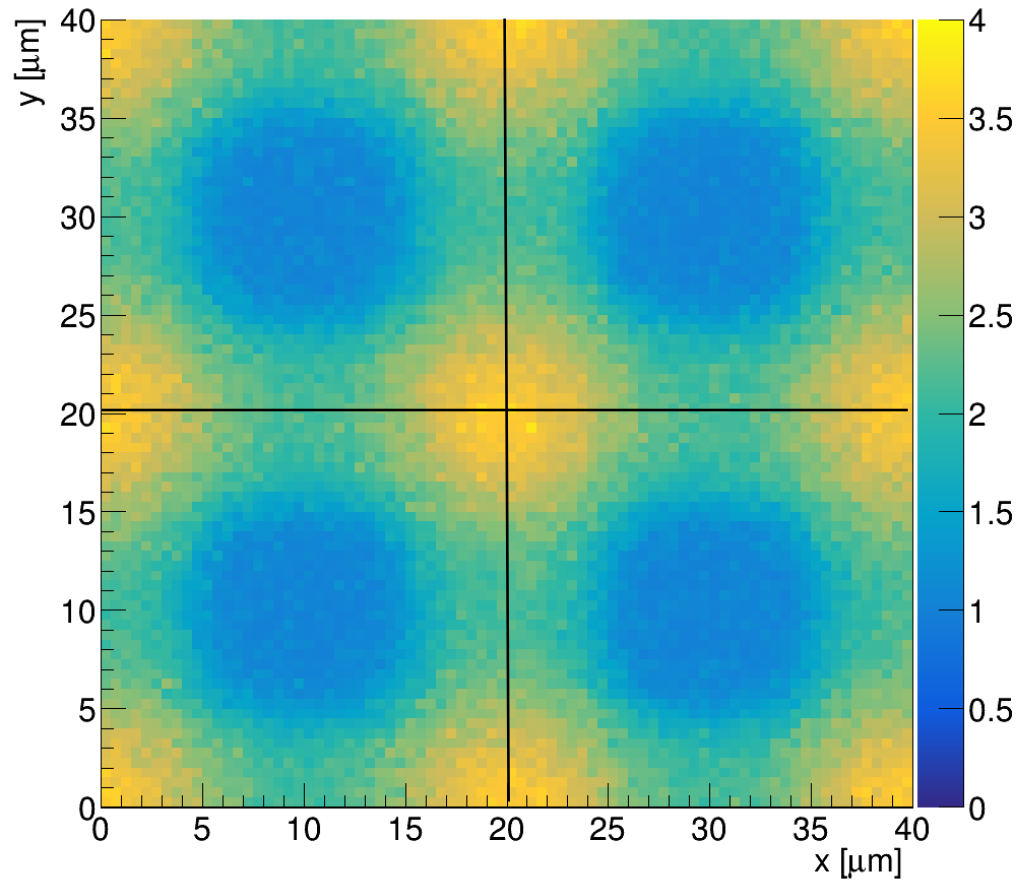


Maximum efficiency at low detection thresholds

Efficiency decreases as we increase the detection threshold

Cluster Size

4 Cluster Size Map , Threshold=80e



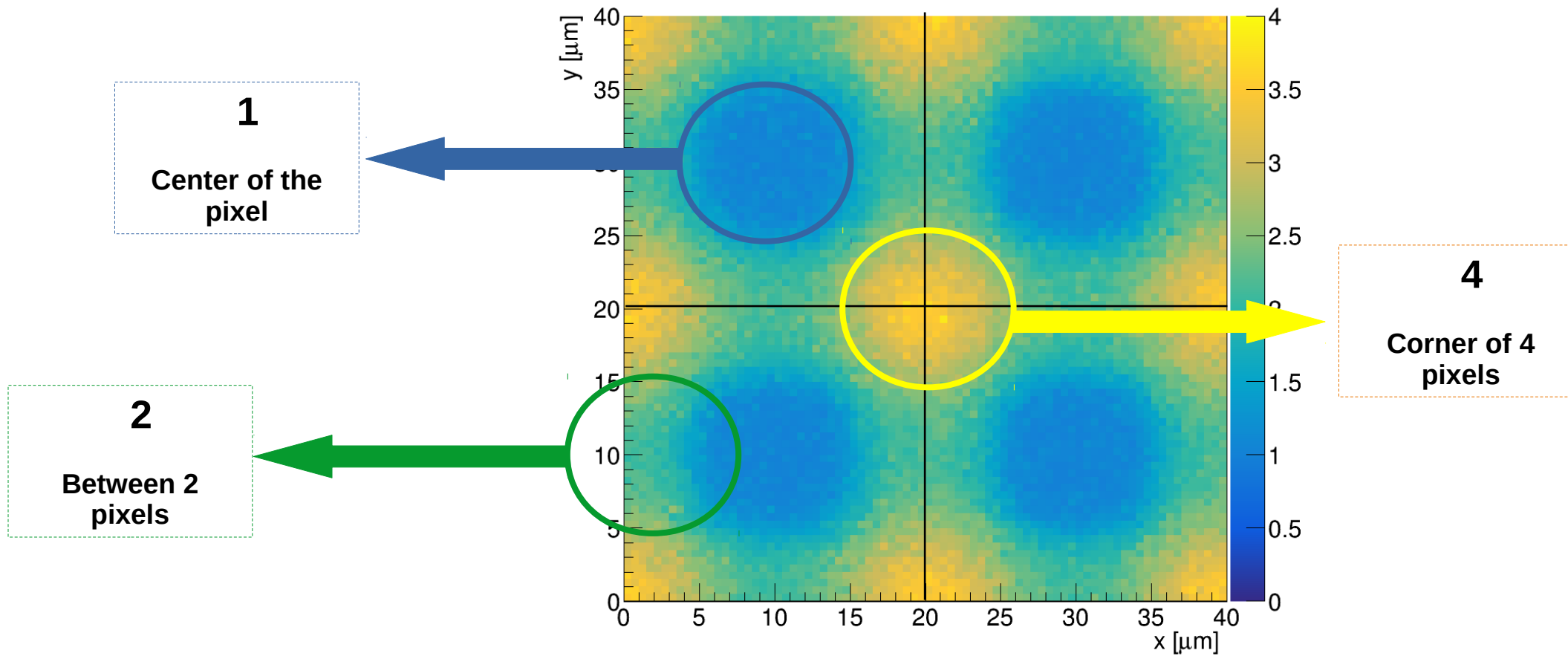
Number of Pixels fired per event.



A high average cluster size translates roughly to a better (smaller) spatial resolution.

Cluster Size (Map of 4 adjacent pixels)

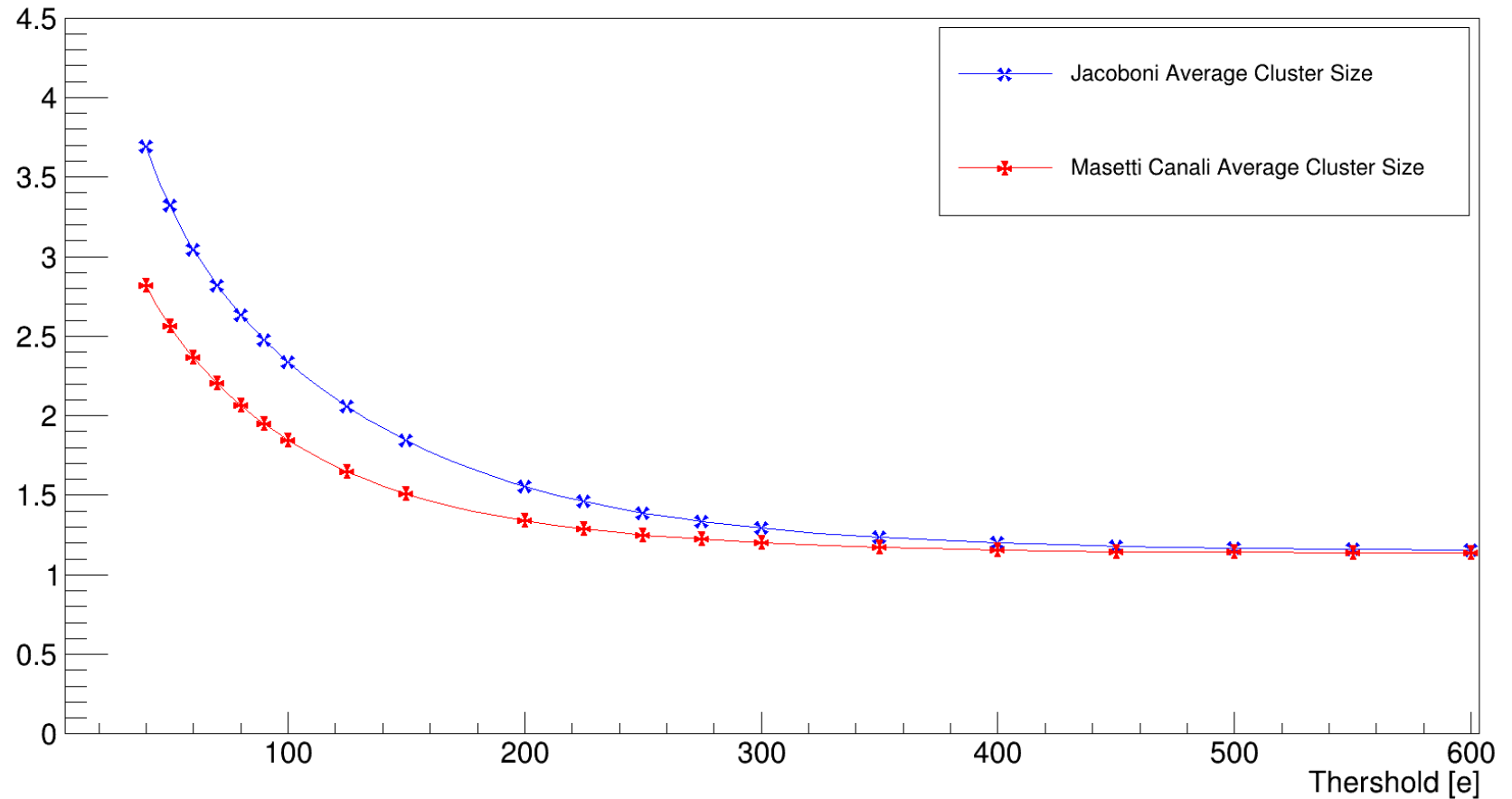
4 Cluster Size Map , Threshold=80e



Cluster Size as a function of the detection threshold

Average Cluster Size

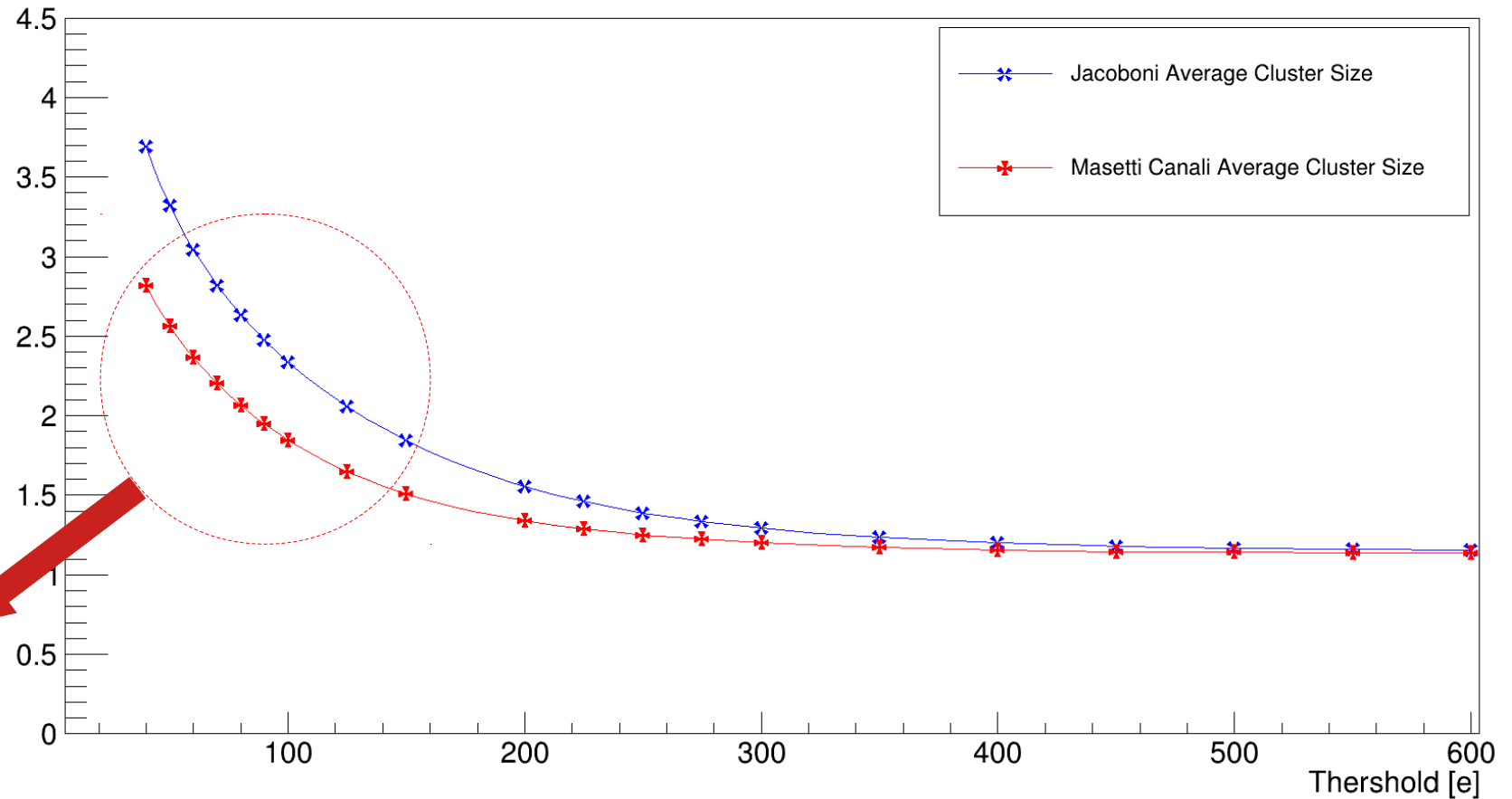
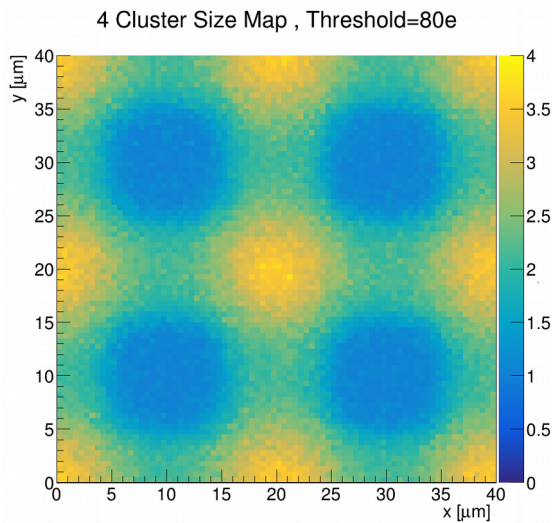
- Non-doping dependent Mobility Model
- Doping dependent Mobility Model



Cluster Size as a function of the detection threshold

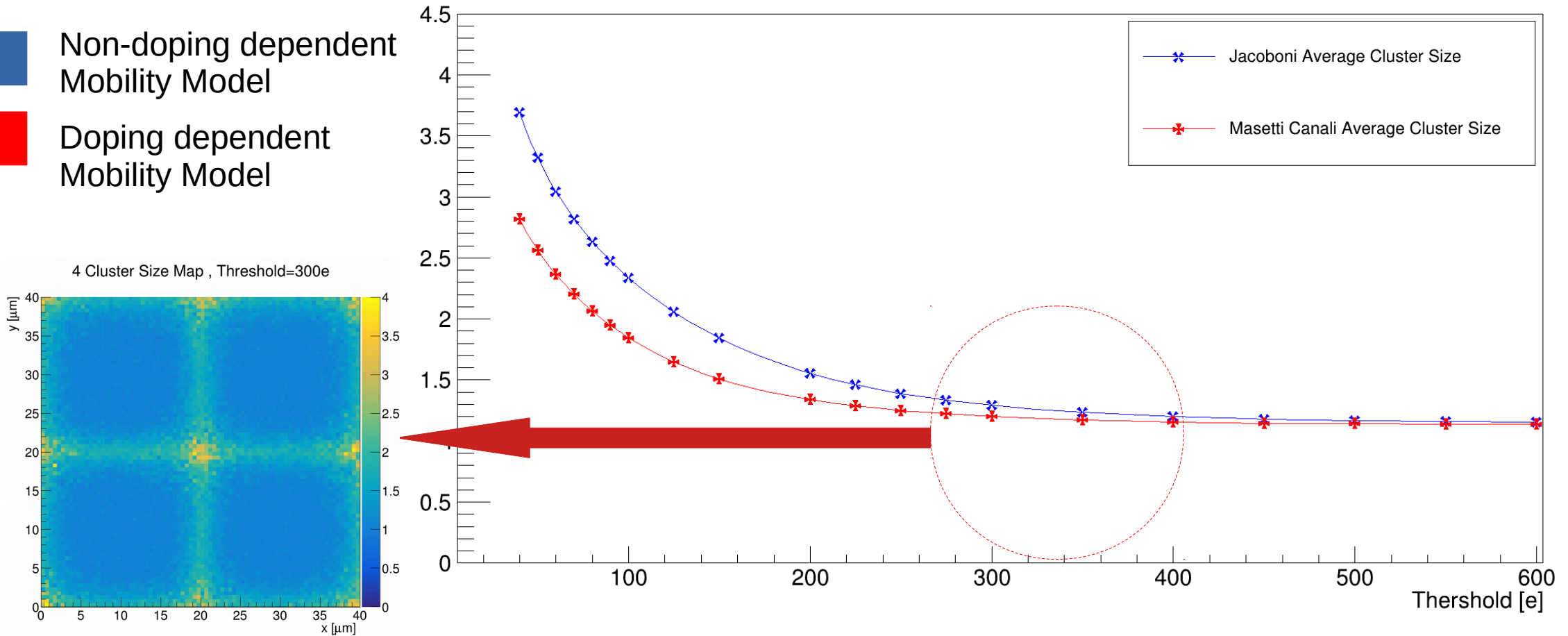
Average Cluster Size

- Non-doping dependent Mobility Model
- Doping dependent Mobility Model

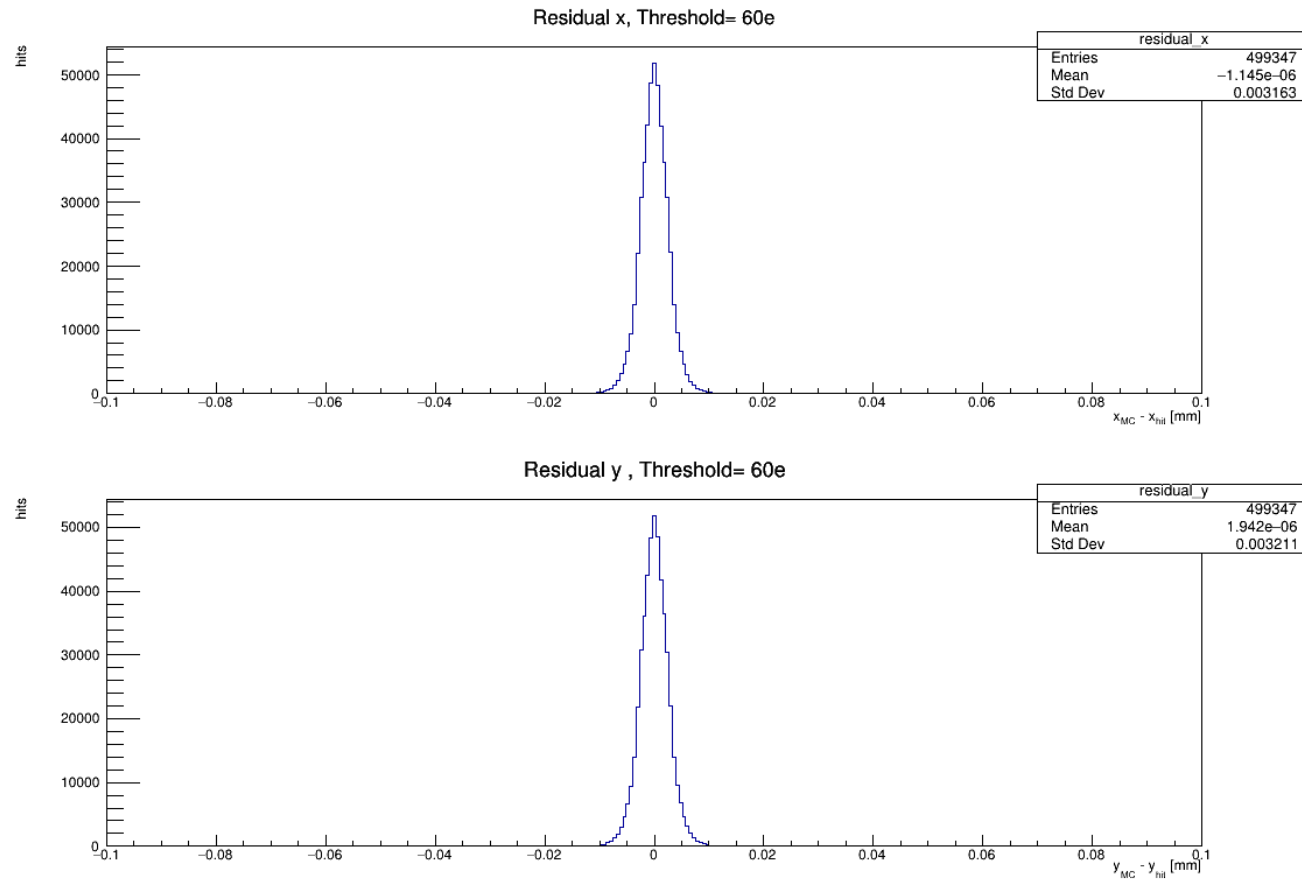


Cluster Size as a function of the detection threshold

Average Cluster Size



Residuals ----> (Spatial Resolution)



Residual: MC Particle incident position – Average cluster position

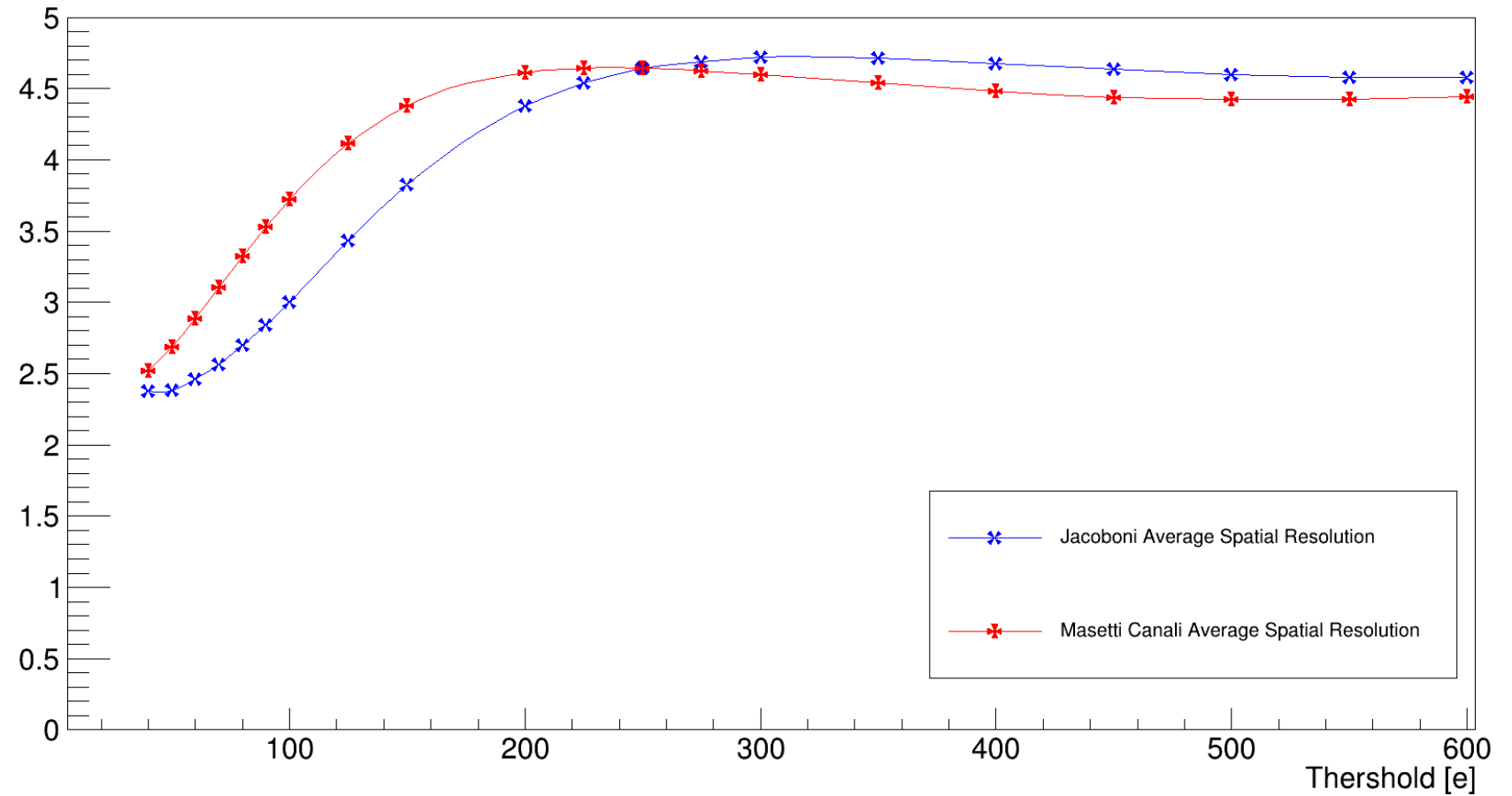


Spatial Resolution:
The RMS of the residual
(or in this case ~ Standard Deviation)

Spatial Resolution as a function of the detection threshold

Average Spatial Resolution [μm]

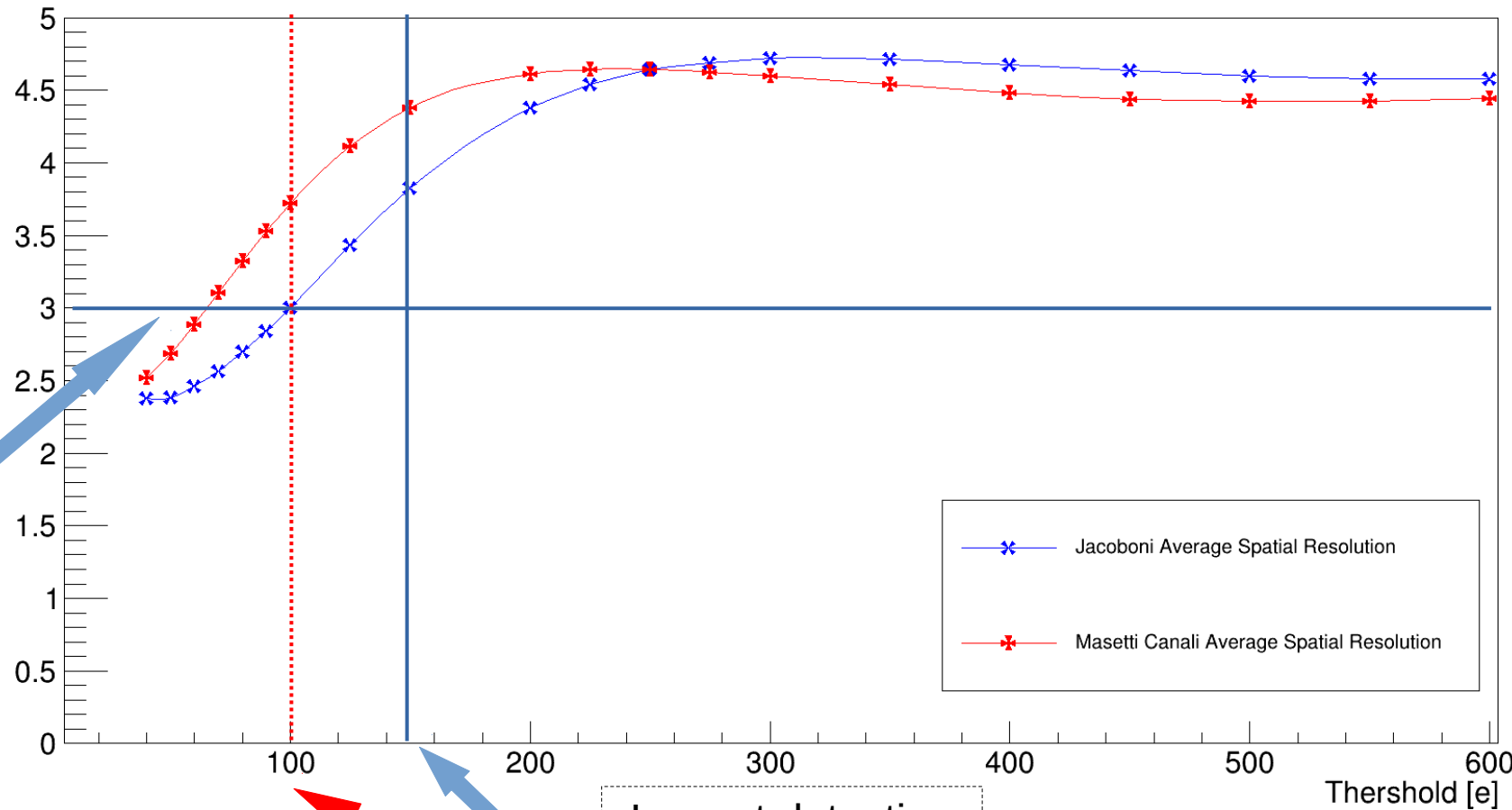
- Non-doping dependent Mobility Model
- Doping dependent Mobility Model



Spatial Resolution as a function of the detection threshold

Average Spatial Resolution [μm]

- Non-doping dependent Mobility Model
- Doping dependent Mobility Model



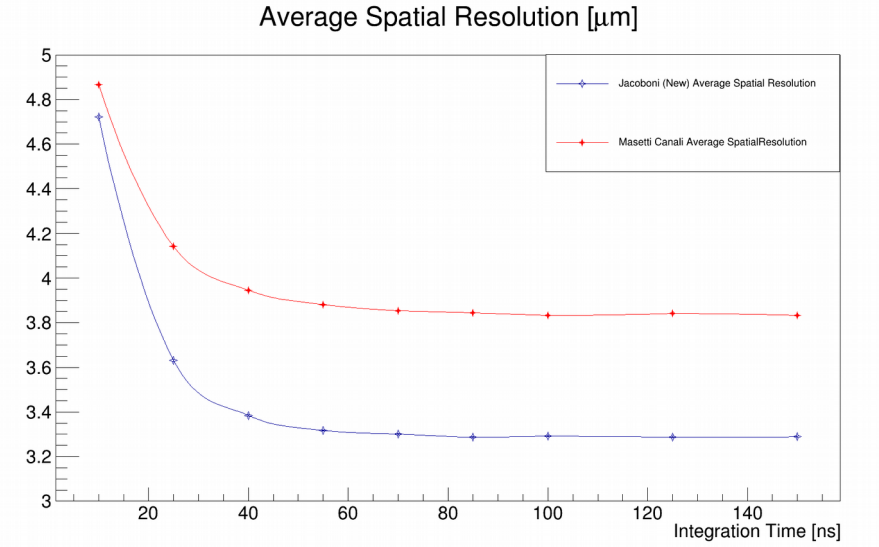
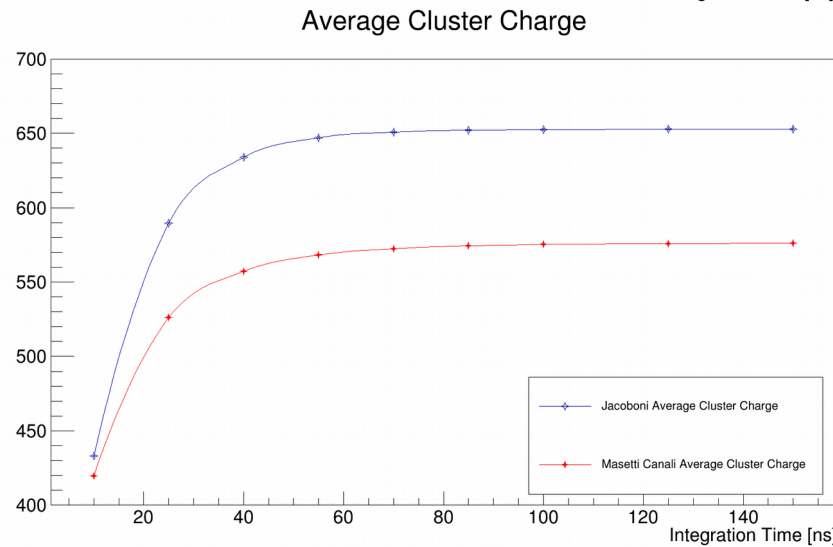
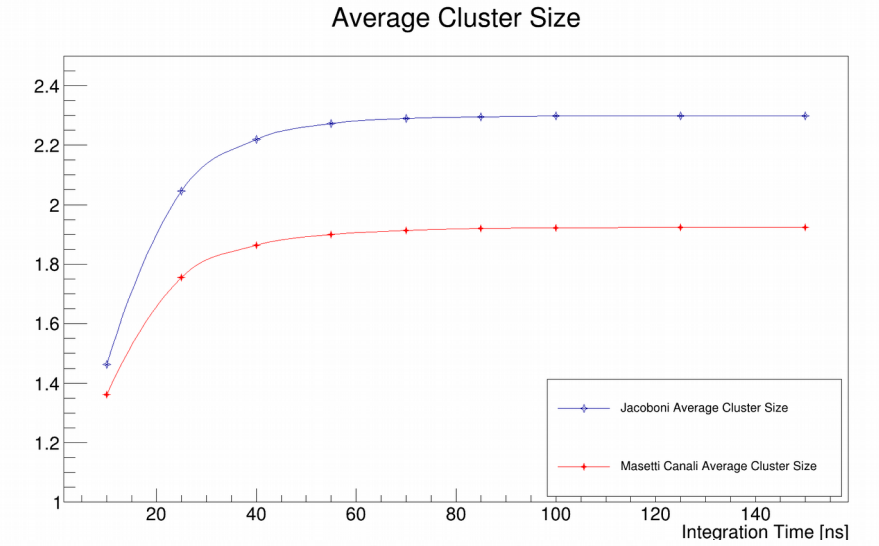
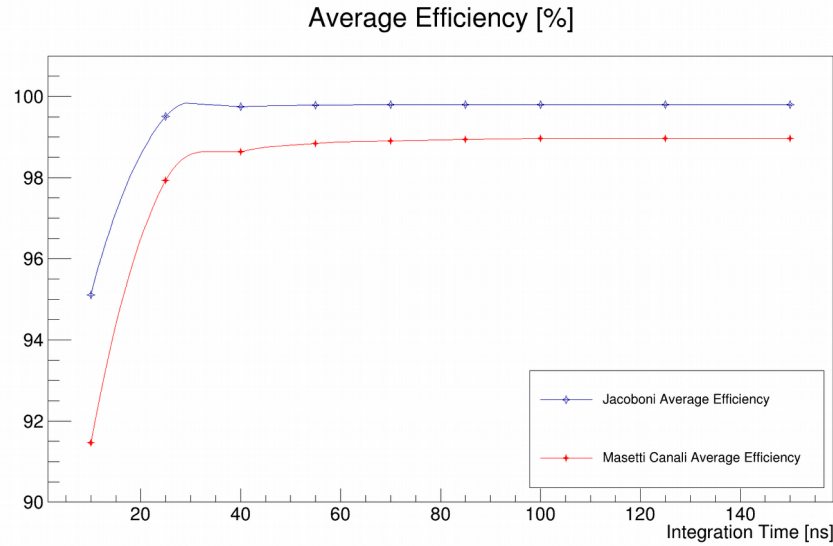
Desired resolution!
What else can we change to achieve this?

Lowest detection threshold is not always possible!
(Noise, electronics)

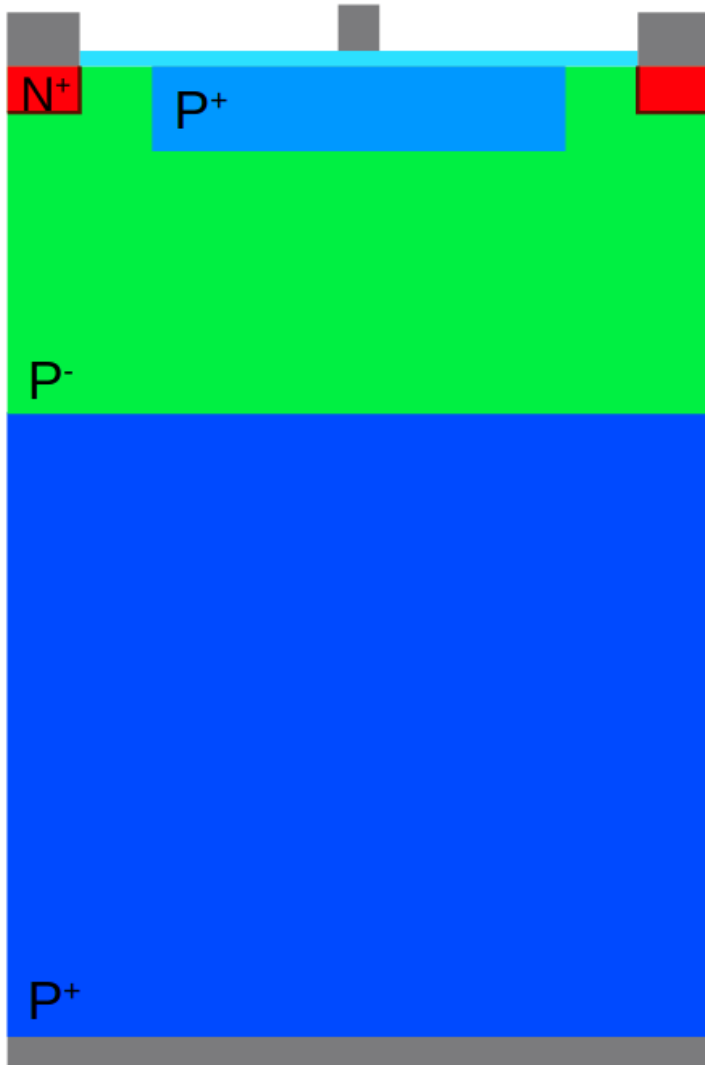


Integration time (Total Simulation time)

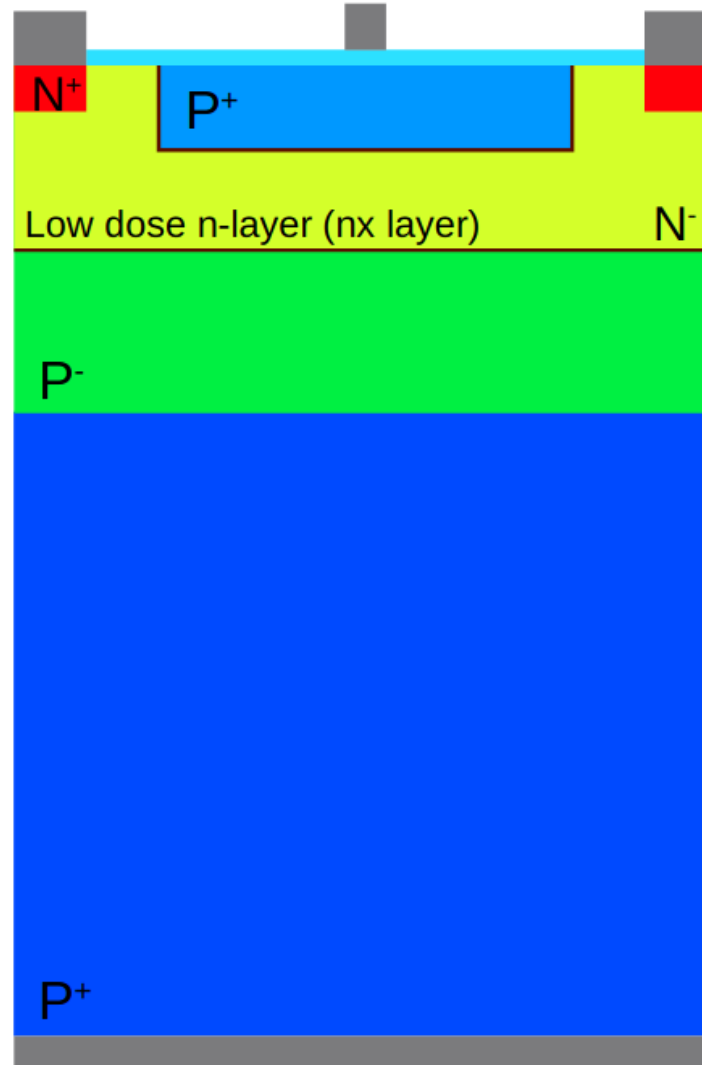
- Non-doping dependent Mobility Model
- Doping dependent Mobility Model



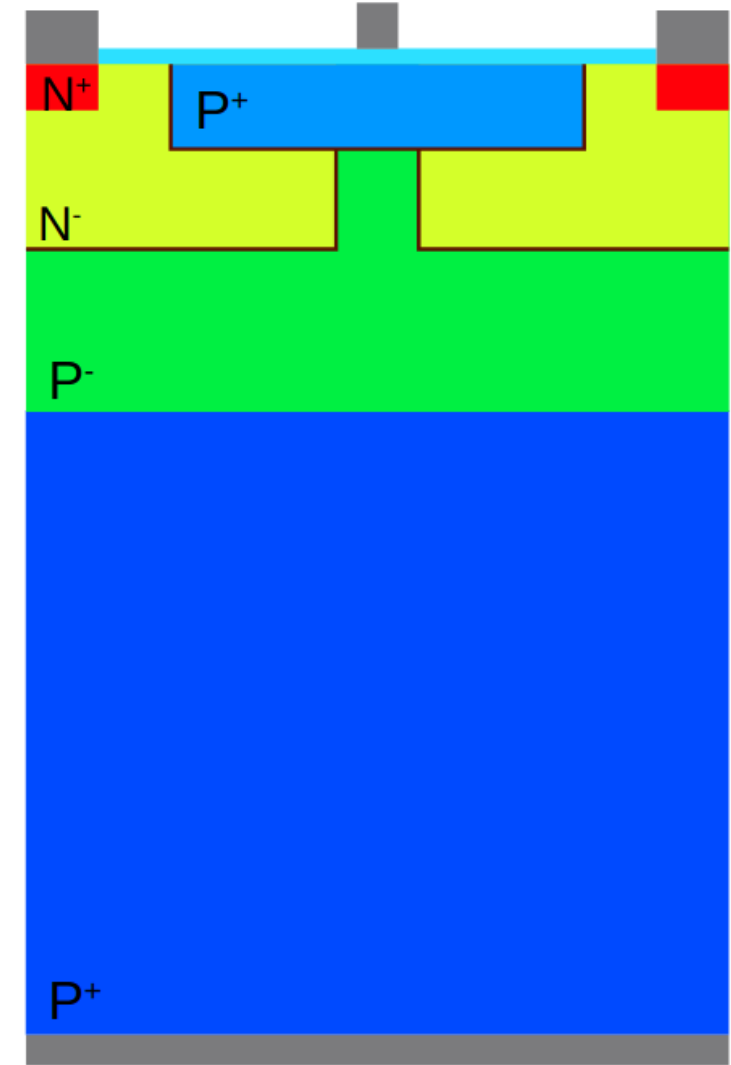
Standard Process



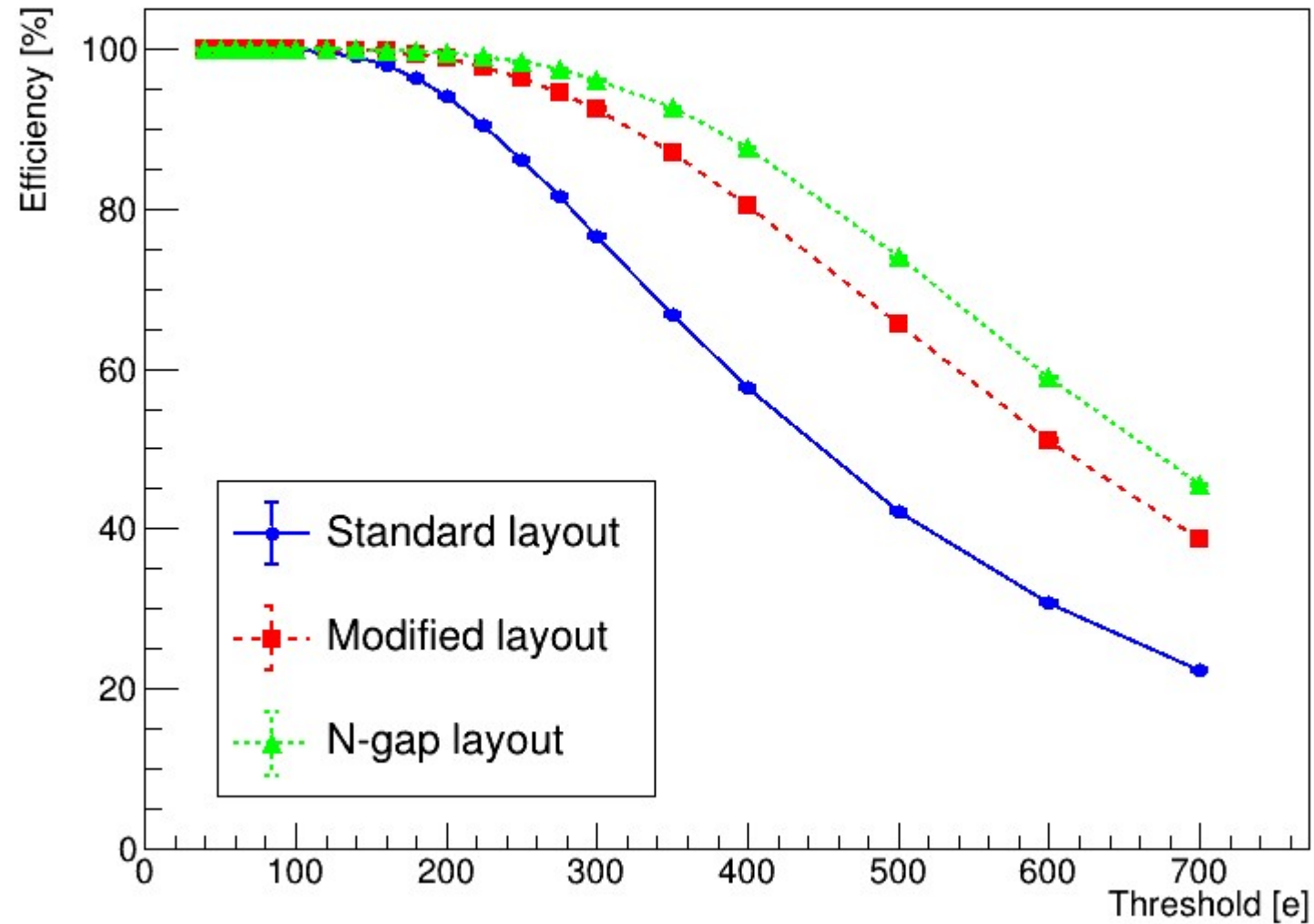
Modified Process



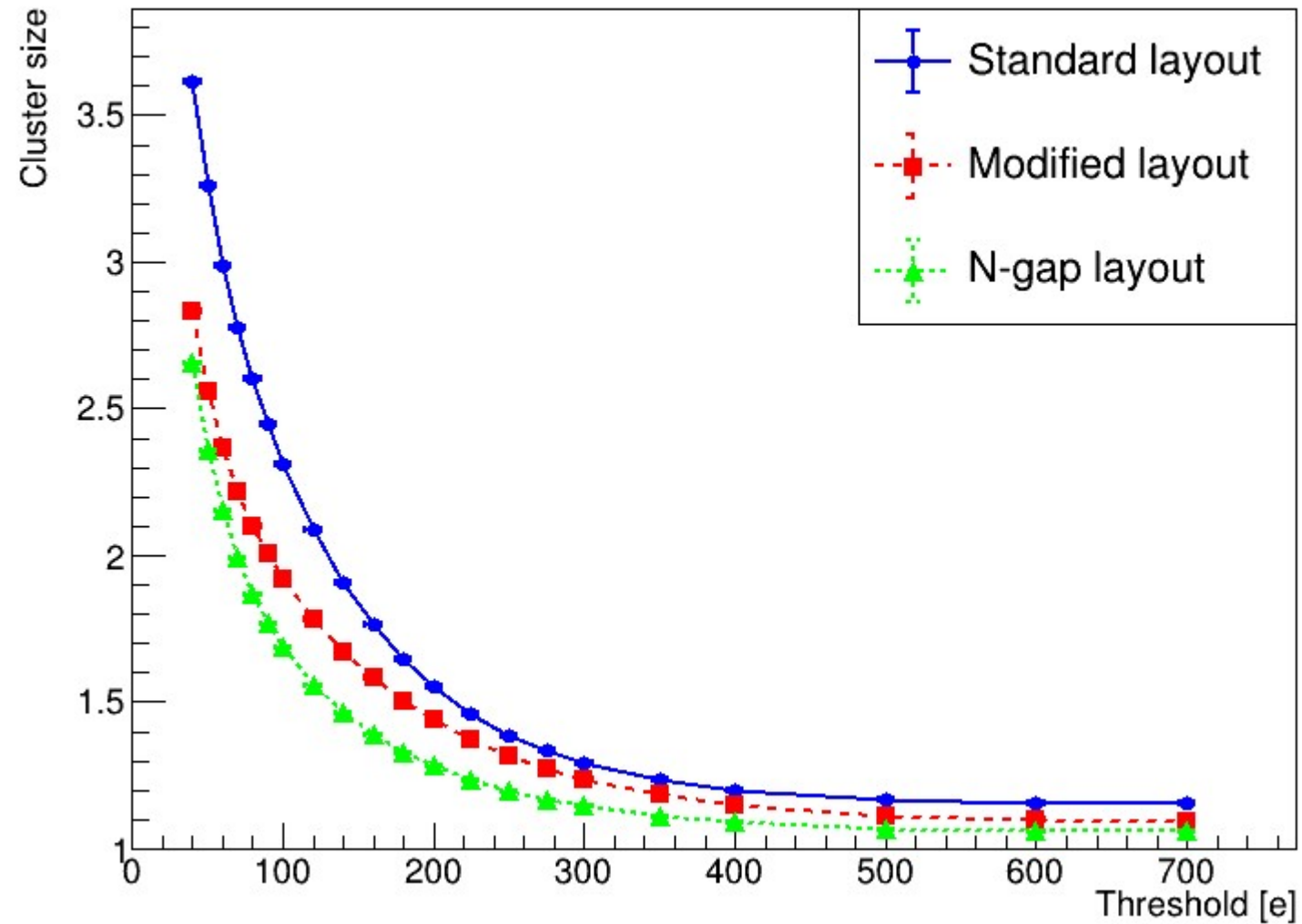
Modified Process with Gap



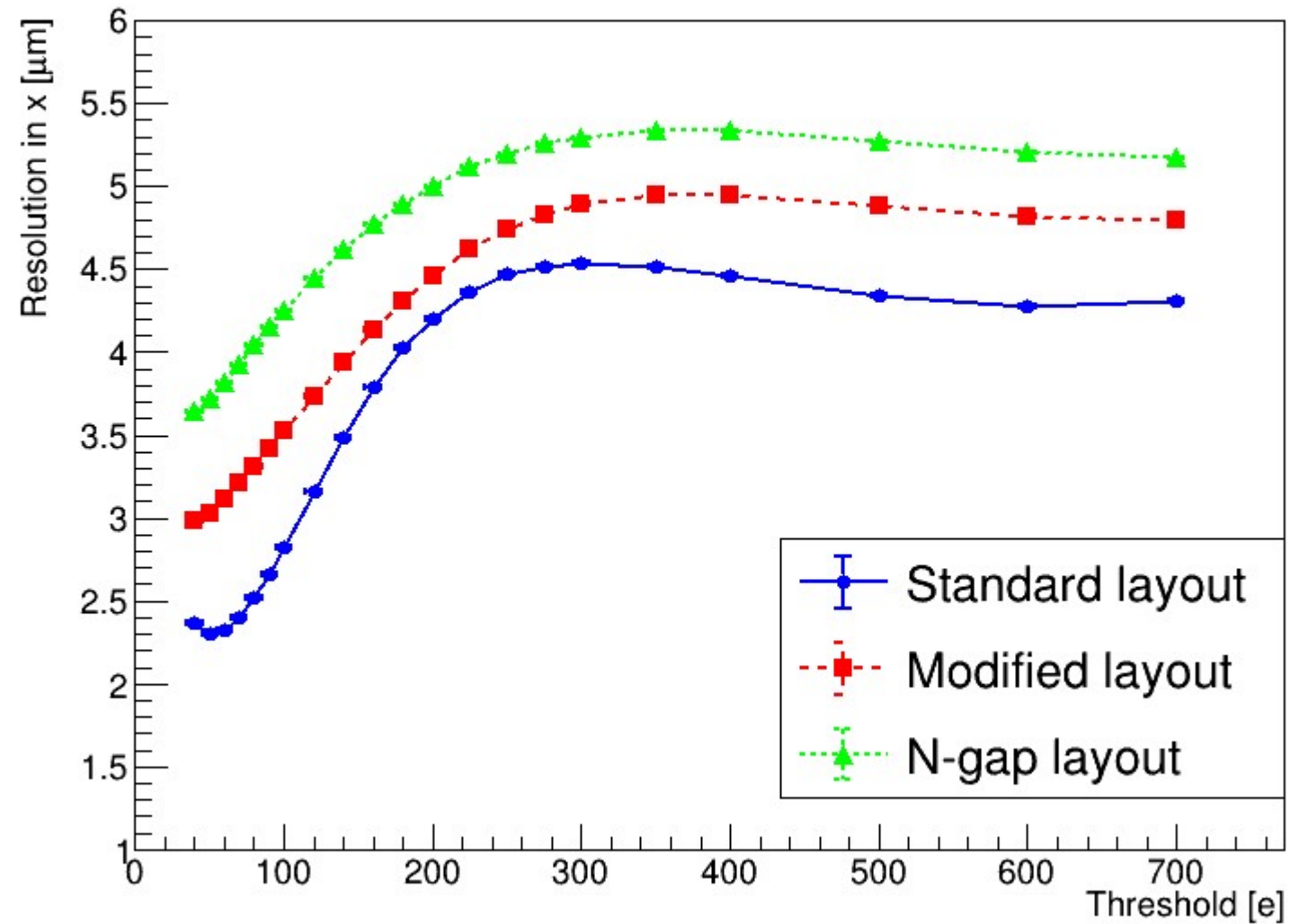
Layouts Comparison



Layouts Comparison



Layouts Comparison



Conclusions and Next Steps!

Conclusions:

- Simulations provide many advantages and benefits.
- Improve from both parts on the simulation (both TCAD and MC).
- There still many parameters that can affect performance that could be worth looking into to achieve the desired capabilities.

Next Steps:

- › Compare results with experimental data.
- › Test the reproducibility, predictability and accuracy of the simulations.
- › Fine tune and refine different parameters to achieve higher accuracy.

Thank you for your time!